

SPICE Device Model Si9407BDY Vishay Siliconix

P-Channel 60-V (D-S) MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

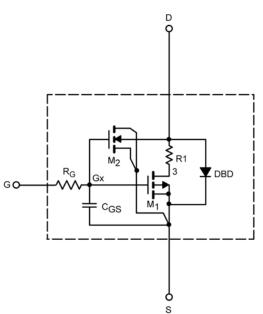
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to 125 °C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the P-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

SUBCIRCUIT MODEL SCHEMATIC

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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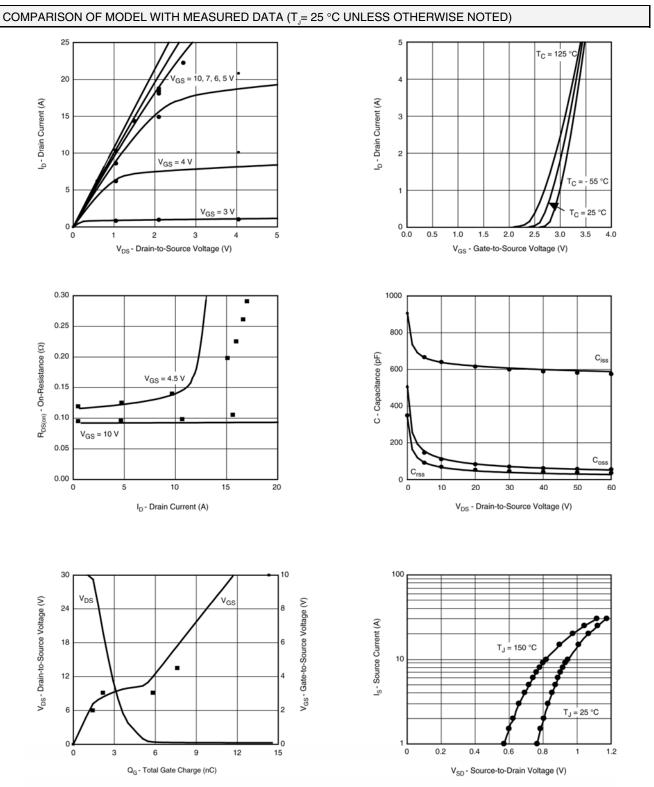


SPECIFICATIONS (T _j = 25 °C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static	-				
Gate Threshold Voltage	V _{GS(th)}	$V_{_{DS}} = V_{_{GS}}$, $I_{_{D}} = -250 \ \mu A$	2.1		V
Drain-Source On-State Resistance®	R _{DS(on)}	$V_{_{GS}}$ = - 10 V, $I_{_{D}}$ = - 3.2 A	0.092	0.100	Ω
		$V_{_{\rm GS}}$ = - 4.5 V, I $_{_{\rm D}}$ = - 2.9 A	0.119	0.126	
Forward Transconductance ^a	9 _{fs}	$V_{_{DS}}$ = - 10 V, $I_{_{D}}$ = - 3.2 A	7.1	8.5	S
Diode Forward Voltage	V _{SD}	I _F = - 2 A	- 0.76	- 0.80	V
Dynamic⁵	-				
Input Capacitance	C _{iss}	$V_{_{DS}}$ = - 30 V, $V_{_{OS}}$ = 0 V, f = 1 MHz	608	600	pF
Output Capacitance	C _{oss}		71	70	
Reverse Transfer Capacitance	C _{rss}		39	50	
Total Gate Charge	Q _g	$V_{_{ m DS}}$ = - 30 V, $V_{_{ m GS}}$ = - 10 V, $I_{_{ m D}}$ = - 3.2 A	12	14.5	nC
		$V_{_{DS}} = -30$ V, $V_{_{GS}} = -4.5$ V, $I_{_{D}} = -3.2$ A	6.4	8	
Gate-Source Charge	Q _{gs}		2.2	2.2	
Gate-Drain Charge	Q_{gd}		3.7	3.7	

Notes a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %. b. Guaranteed by design, not subject to production testing.



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Note: Dots and squares represent measured data.



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